M. Tech. I Semester Regular/Supple Examinations, Jan/Feb -2018

CMOS ANALOG IC DESIGN

Common to VLSI&ES (68), ES&VLSI (48), VLSID &ES (77), ES &VLSID (81), VLSI (57), VLSID (72), VLSI System Design (61), VLSI & Micro Electronics (76)

Time: 3	6 Hours
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Max. Marks: 60

	Answer any FIVE Questions All Questions Carry Equal Marks				
1.	a	Write a brief note on various passive components that are available in CMOS technologies with relevant diagrams	8M		
	b	With necessary schematics, explain the term Latch up in CMOS Technology	4M		
2.	a b	Draw the model for a non ideal switch and explain its parameters in detail Draw and explain about a simple current mirror with Beta helper.			
3.	a b	Draw and explain the circuit diagram for voltage reference with high sensitivity Explain the Inverter DC characteristics and also give your inference on MOSFET channel length	5M 7M		
4.	a b	With relevant expressions explain the terms maximum and minimum differential i/p voltage $ \frac{5 V}{i_{D1}} = \frac{5 V}{i_{D2}} $	6M 6M		



Estimate the maximum and minimum voltage on the gate of MI in Fig. that ensures that neither MI or M2 shut off.(Assume the necessary data)

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5.		With the necessary schematics explain the following terms	
		i) Simple folded cascode	4M
		ii) Folded cascode with biasing	4M
		iii) Folded cascode with nMOS input	4M
6.	а	With a schematic explain about operational-amplifier with its equivalent circuit	4M
	b	Define and explain the following terms	8M
	U	i) Common-Mode Input Range	
		ii) Common-Mode Rejection Ratio	
7.	a	Draw the schematic for a Folded-cascode op-amp with class AB output buffer and explain its operation	6M
	b	Draw the Block diagram of a spectrum analyzer and explain the procedure to measure the spectral content of a signal	6M
8.	а	Write a note on characterization of comparator	5M
	b	With relevant schematics explain about discrete-time comparators.	7M

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